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Bib Data Sheet

CONFIRMATION NO. 6761

SERIAL NUMBER 09/856,212	FILING OR 371(c) DATE 05/18/2001 RULE	CLASS 117	GROUP ART UNIT 1722	ATTORNEY DOCKET NO. 82821
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** CONTINUING DATA *****

This application is a 371 of PCT/JP99/06477 11/19/1999 M2

** FOREIGN APPLICATIONS *****

JAPAN 10/330713 11/20/1998

JAPAN 11/77166 03/23/1999 M2

JAPAN 11/129957 05/11/1999

Foreign Priority claimed	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no
35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance
Verified and Acknowledged	<i>Mas</i> Examiner's Signature <i>M2</i> Initials
STATE OR COUNTRY	JAPAN
SHEETS DRAWING	16
TOTAL CLAIMS	23
INDEPENDENT CLAIMS	15

ADDRESS

24628

TITLE

Production method for silicon single crystal and production device for single crystal ingot, and heat treating method for silicon single crystal wafer

FILING FEE RECEIVED 1874	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees
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